



10-Channel Gamma Buffer with V_{COM} Driver

ADD8710

FEATURES

- Single-supply operation: 4.5 V to 18 V
- Upper/lower buffers swing to V_S /GND
- Gamma continuous output current: >10 mA
- V_{COM} peak output current: 250 mA
- Offset voltage: 12 mV
- Slew rate: 8 V/ μ s
- Unity gain stable with large capacitive loads
- Supply current: 700 μ A per amplifier
- Compact 28-lead TSSOP
- Pb-free package
- Drop-in replacement for BUF11702

APPLICATIONS

- TFT LCD monitor panels
- TFT LCD notebook panels

GENERAL DESCRIPTION

The ADD8710 is a low cost, 10-channel gamma buffer with a V_{COM} driver that operates from a single supply. The part is designed for high resolution TFT LCD panels and is built on an advanced, high voltage CBCMOS process.

The gamma buffers have a high slew rate, minimum 10 mA output current, and a high capacitive load drive capability. The V_{COM} buffer is capable of delivering 250 mA of peak current and can also drive large capacitive loads. The ADD8710 offers a wide supply range and offset voltages below 12 mV.

The ADD8710 is specified over the -40°C to $+85^{\circ}\text{C}$ temperature range and is available in a Pb-free, 28-lead TSSOP package.

PIN CONFIGURATION

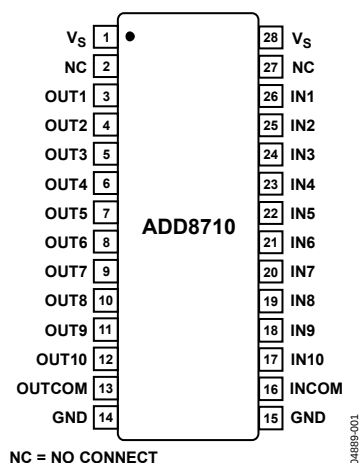


Figure 1. 28-Lead TSSOP (RU Suffix)

FUNCTIONAL BLOCK DIAGRAM

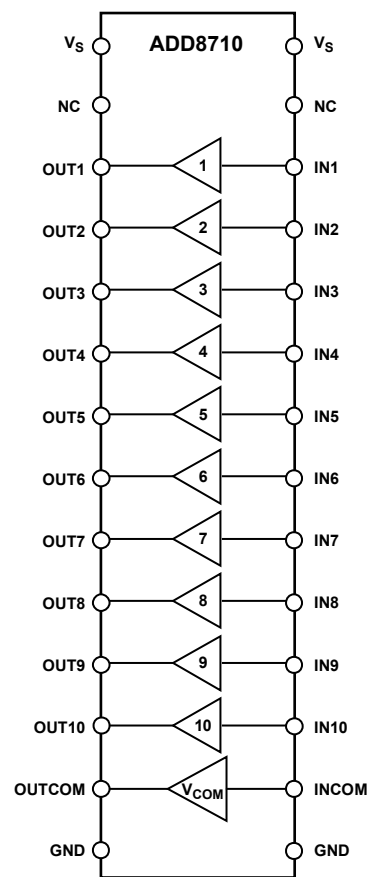


Figure 2.

Rev. B

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REVISION HISTORY

6/07—Rev. A to Rev. B	
Changes to Figure 18.....	7
3/05—Rev. 0 to Rev. A	
Change to Features	1
Changes to Specifications.....	3
Change to Absolute Maximum Ratings.....	4
6/04—Revision 0: Initial Version	

SPECIFICATIONS

$V_S = 16\text{ V}$, $V_{CM} = V_S/2$, $T_A @ 25^\circ\text{C}$, unless otherwise noted.

Table 1.

Parameter	Symbol	Condition	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	Applies to all channels		4	12	mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		5		$\mu\text{V}/^\circ\text{C}$
Input Bias Current	I_B	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		0.5	1.1	μA
					1.5	μA
Input Impedance	Z_{IN}			400		k Ω
Input Capacitance	C_{IN}			1		pF
BUFFER CHARACTERISTICS						
Common-Mode Input Range	V_{CMM}		1.25		V_S	V
Buffer 1 to Buffer 5			0		$V_S - 1.25$	V
Buffer 6 to Buffer 10						
Output Voltage High (V1)	V_{OH}	$V_S = 16\text{ V}$, $V_{IN} = 16\text{ V}$, $I_L = 10\text{ mA}$	15.82	15.9		V
		$V_S = 10\text{ V}$, $V_{IN} = 9.8\text{ V}$, $I_L = 10\text{ mA}$	9.75	9.8		V
		$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	9.7			V
Output Voltage High (V2 to V5)	V_{OH}	$V_S = 10\text{ V}$, $V_{IN} = 8.5\text{ V}$, $I_L = 10\text{ mA}$	8.45	8.5		V
		$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	8.4			V
Output Voltage High (V6 to V10)	V_{OH}	$V_S = 10\text{ V}$, $V_{IN} = 8\text{ V}$, $I_L = 10\text{ mA}$	7.95	8		V
		$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	7.9			V
Output Voltage Low (V1 to V5)	V_{OL}	$V_S = 10\text{ V}$, $V_{IN} = 2\text{ V}$, $I_L = 10\text{ mA}$		2	2.05	V
		$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$			2.10	V
Output Voltage Low (V6 to V9)	V_{OL}	$V_S = 10\text{ V}$, $V_{IN} = 1.5\text{ V}$, $I_L = 10\text{ mA}$		1.5	1.55	V
		$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$			1.60	V
Output Voltage Low (V10)	V_{OL}	$V_S = 16\text{ V}$, $V_{IN} = 0\text{ V}$, $I_L = 10\text{ mA}$		0.1	0.175	V
		$V_S = 10\text{ V}$, $V_{IN} = 0.2\text{ V}$, $I_L = 10\text{ mA}$		0.2	0.25	V
		$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		0.3		V
Continuous Output Current	I_{OUT}			10		mA
Peak Output Current	I_{PK}	$V_S = 16\text{ V}$		100		mA
V_{COM} CHARACTERISTICS						
Common-Mode Input Range	V_{CMM}		0		$V_S - 1.25$	V
Output Voltage High	V_{OH}	$V_S = 10\text{ V}$, $V_{IN} = 8\text{ V}$, $I_L = 30\text{ mA}$	7.95	8		V
		$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	7.9			V
Output Voltage Low	V_{OL}	$V_S = 10\text{ V}$, $V_{IN} = 2\text{ V}$, $I_L = 30\text{ mA}$		2	2.05	V
		$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$			2.10	V
Continuous Output Current	I_{OUT}			35		mA
Peak Output Current	I_{PK}	$V_S = 16\text{ V}$		250		mA
SUPPLY CHARACTERISTICS						
Supply Voltage	V_S		4.5		18	V
Power Supply Rejection Ratio	PSRR	$V_S = 4.5\text{ V to } 16.5\text{ V}$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	70	90		dB
Total Supply Current	I_{SY}	$V_O = V_S/2$, no load		7.7	10	mA
		$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$			11.5	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$, $C_L = 200\text{ pF}$	4	8		V/ μs
Bandwidth	BW	-3 dB , $R_L = 10\text{ k}\Omega$, $C_L = 200\text{ pF}$		5		MHz
Settling Time to 0.1% (Buffers)	t_s	1 V step, $R_L = 10\text{ k}\Omega$, $C_L = 200\text{ pF}$		1.1		μs
Settling Time to 0.1% (V_{COM})	t_s	1 V step, $R_L = 10\text{ k}\Omega$, $C_L = 200\text{ pF}$		0.7		μs
Phase Margin	Φ_O	$R_L = 10\text{ k}\Omega$, $C_L = 200\text{ pF}$		45		Degrees
Channel Separation				75		dB

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Supply Voltage (V_S)	18.5 V
Input Voltage	−0.5 V to $V_S + 0.5$ V
Storage Temperature Range	−65°C to +150°C
Operating Temperature Range	−40°C to +85°C
Junction Temperature Range	−65°C to +150°C
Lead Temperature	300°C
ESD Tolerance (HBM)	±2500 V
ESD Tolerance (MM)	±200 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 3. Thermal Resistance

Package Type	θ_{JA}	Unit
28-Lead TSSOP (RU)	67.7	°C/W

ESD CAUTION



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

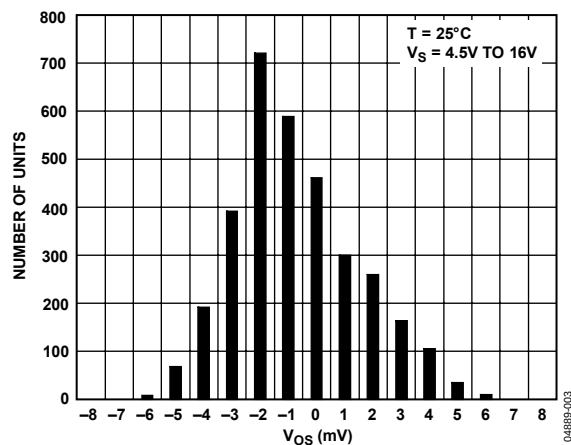


Figure 3. Input Offset Voltage Distribution

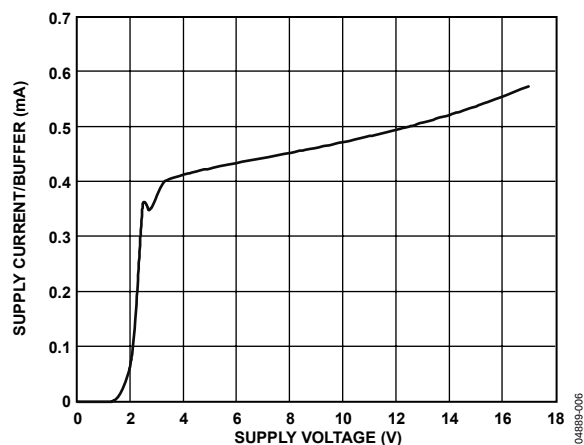


Figure 6. Supply Current/Buffer vs. Supply Voltage

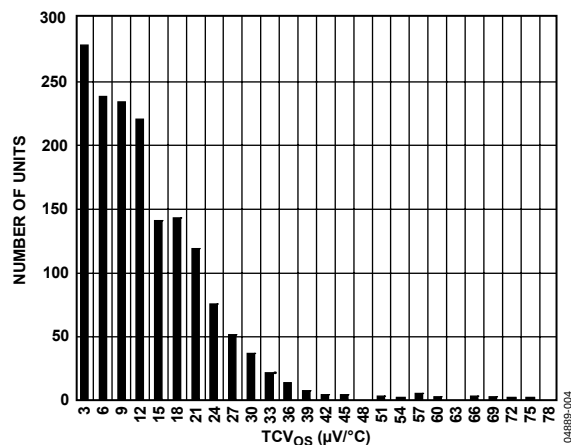


Figure 4. Input Offset Voltage Drift Distribution

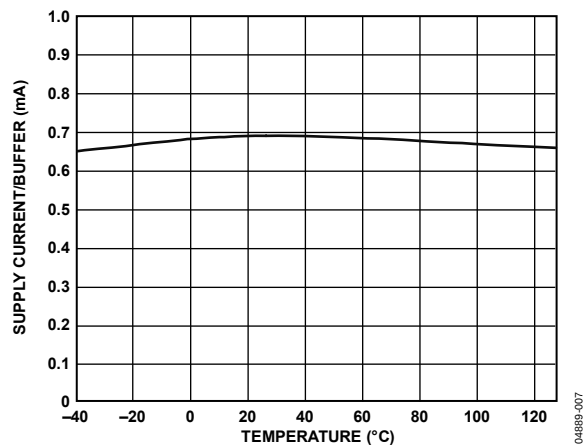


Figure 7. Supply Current/Buffer vs. Temperature

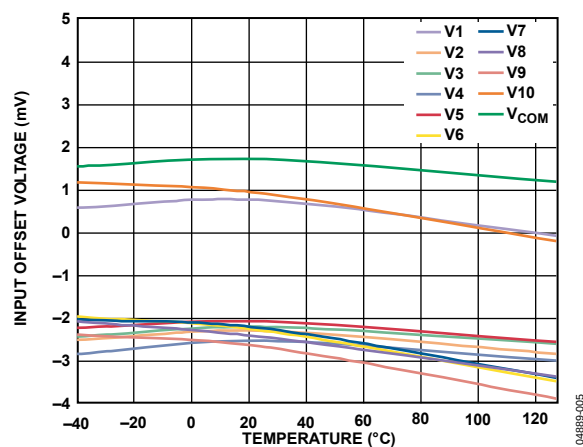


Figure 5. Input Offset Voltage vs. Temperature

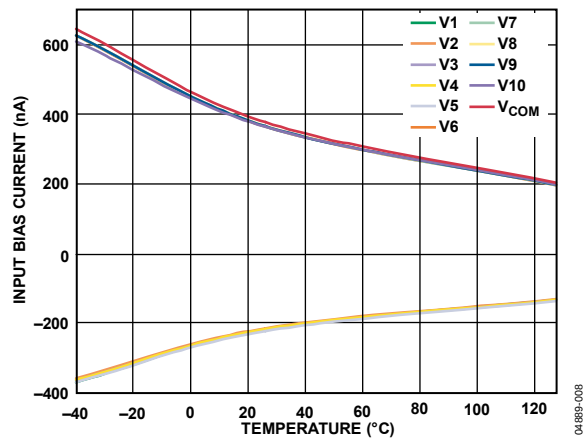


Figure 8. Input Bias Current vs. Temperature

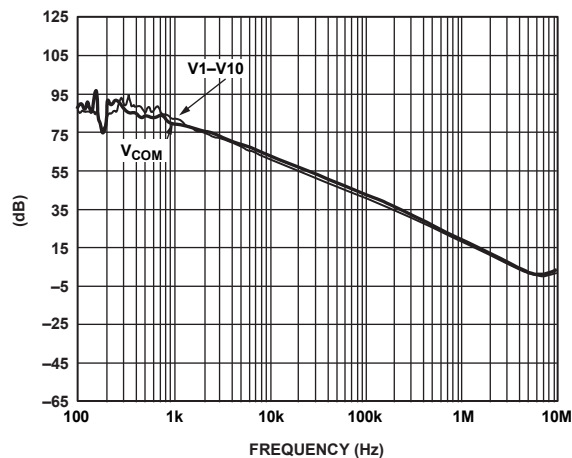


Figure 9. Power Supply Rejection Ratio vs. Frequency

04889-009

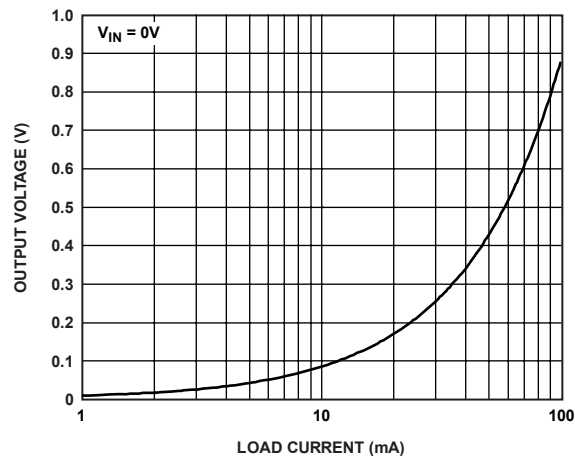


Figure 12. Channel V_{COM} Output Voltage Low vs. Load Current

04889-012

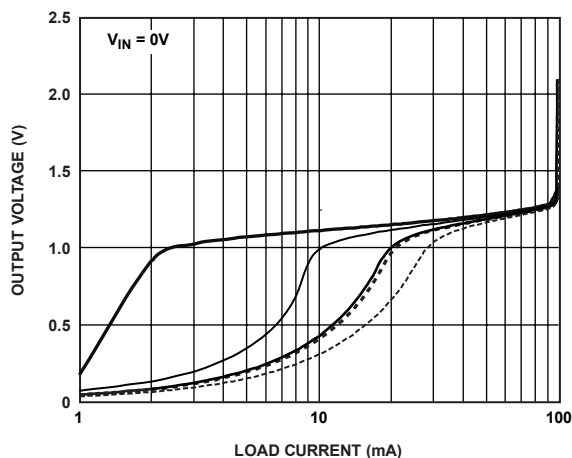


Figure 10. Channel 1 to Channel 5 Output Voltage Low vs. Load Current

04889-010

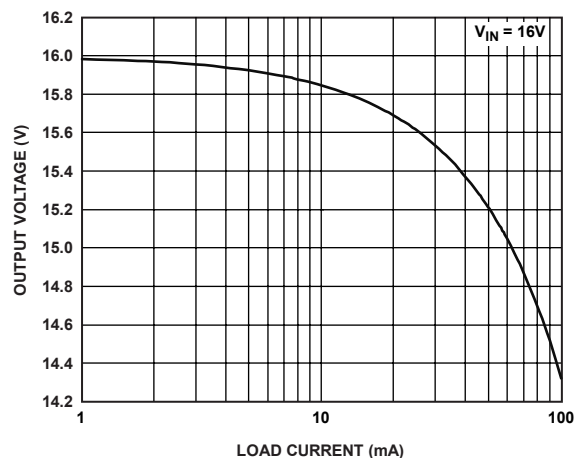


Figure 13. Channel 1 Output Voltage High vs. Load Current

04889-013

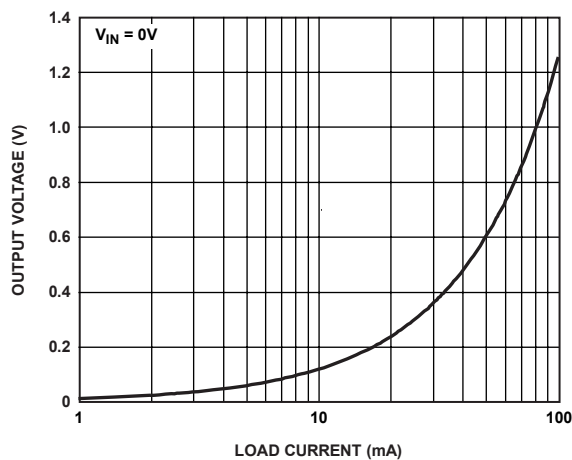


Figure 11. Channel 6 to Channel 10 Output Voltage Low vs. Load Current

04889-011

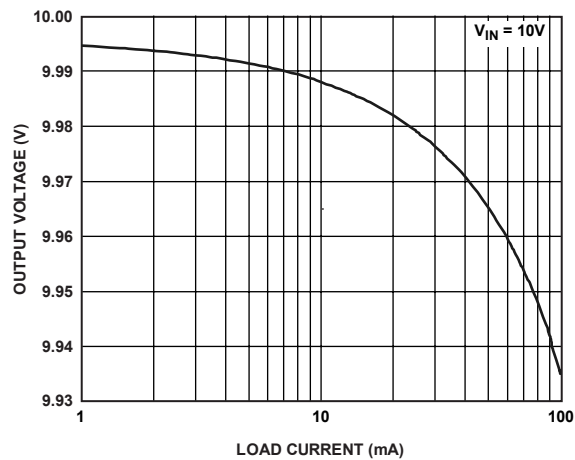


Figure 14. Channel 2 to Channel 5 Output Voltage High vs. Load Current

04889-014

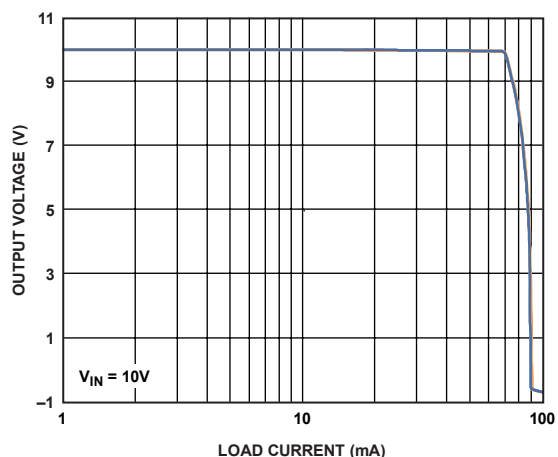


Figure 15. Channel 6 to Channel 10 Output Voltage High vs. Load Current

04889-015

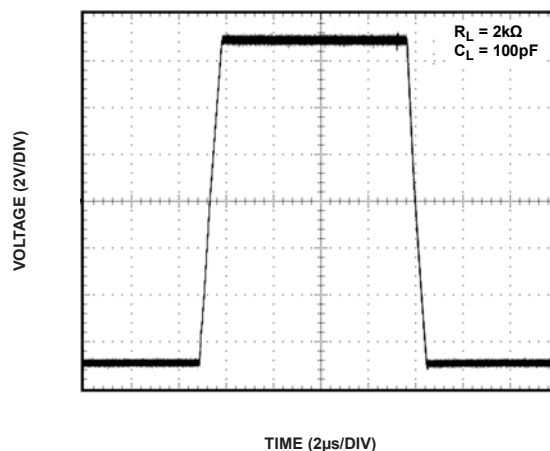


Figure 18. Large Signal Transient Response

04889-018

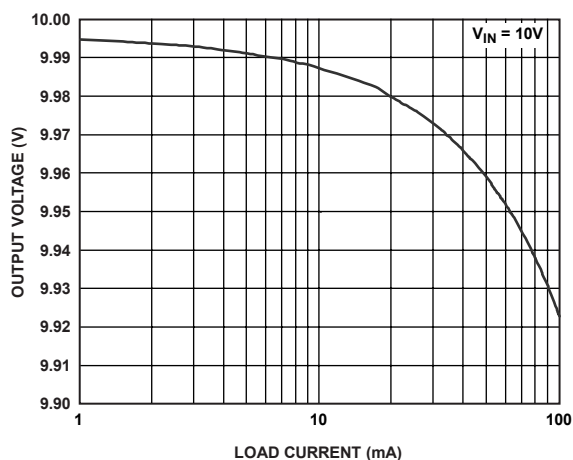


Figure 16. Channel V_{COM} Output Voltage High vs. Load Current

04889-016

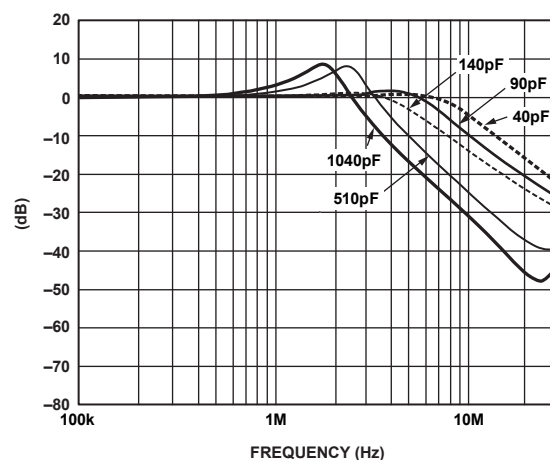


Figure 19. Channel 1 to Channel 5 Frequency Response vs. Capacitive Loading

04889-019

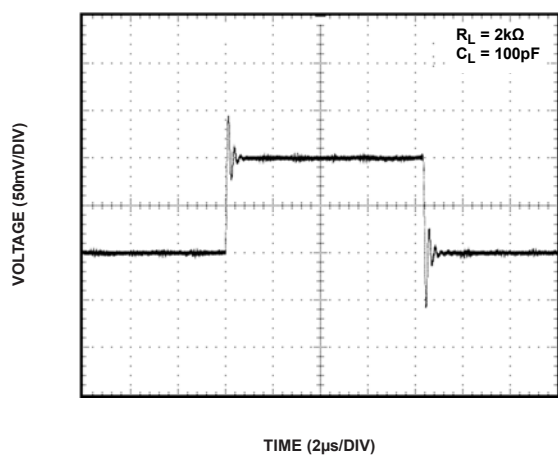


Figure 17. Small Signal Transient Response

04889-017

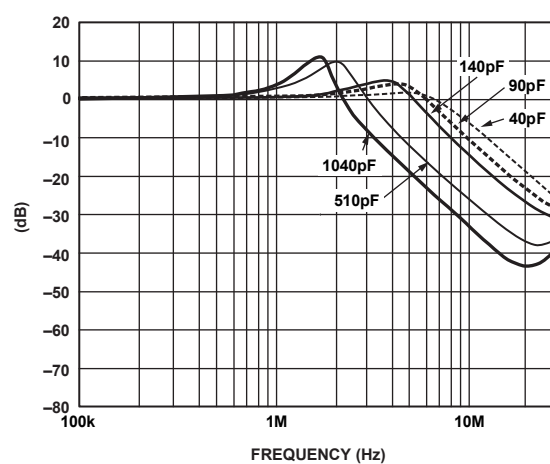
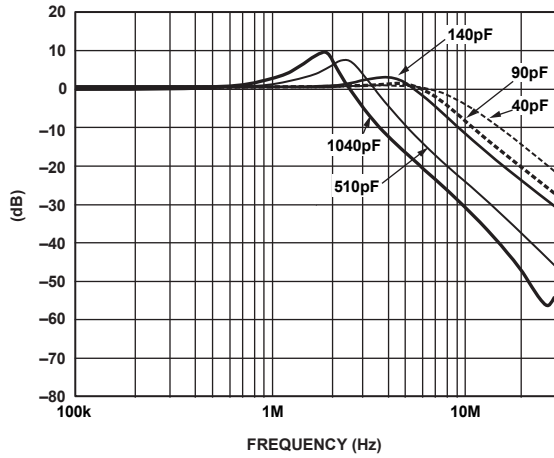


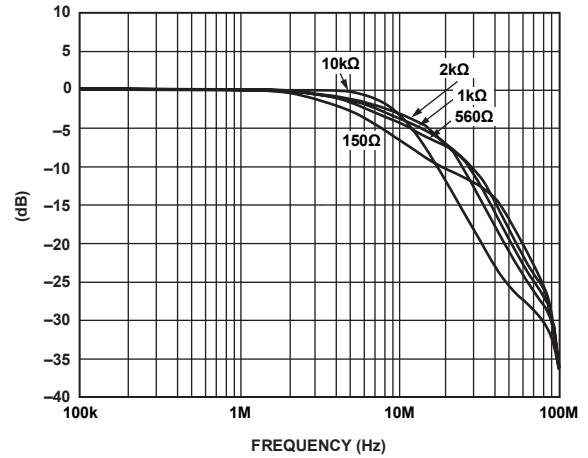
Figure 20. Channel 6 to Channel 10 Frequency Response vs. Capacitive Loading

04889-020



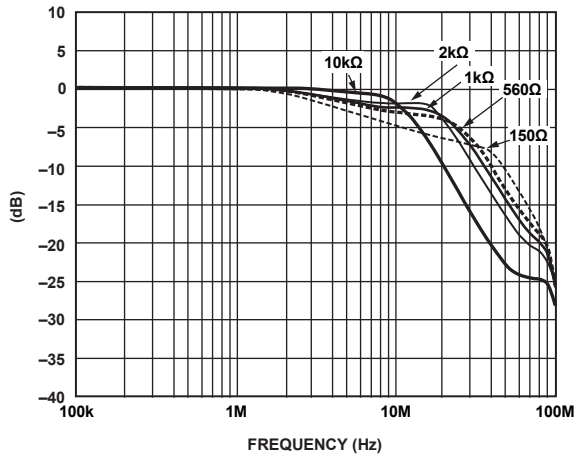
04889-021

Figure 21. Channel V_{COM} Frequency Response vs. Capacitive Loading



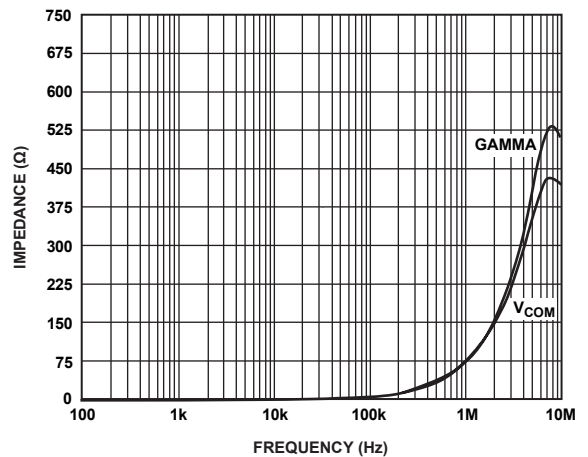
04889-024

Figure 24. Channel V_{COM} Frequency Response vs. Resistive Loading



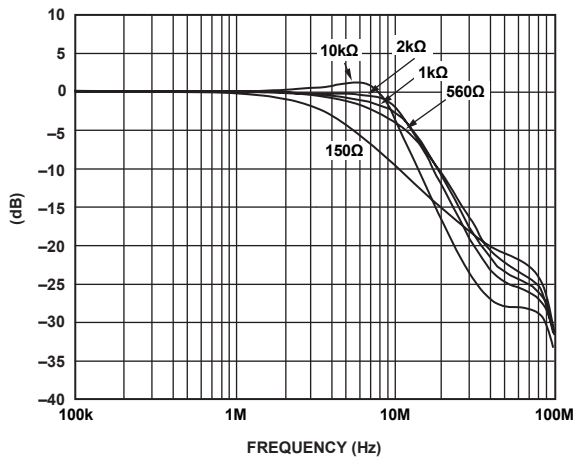
04889-022

Figure 22. Channel 1 to Channel 5 Frequency Response vs. Resistive Loading



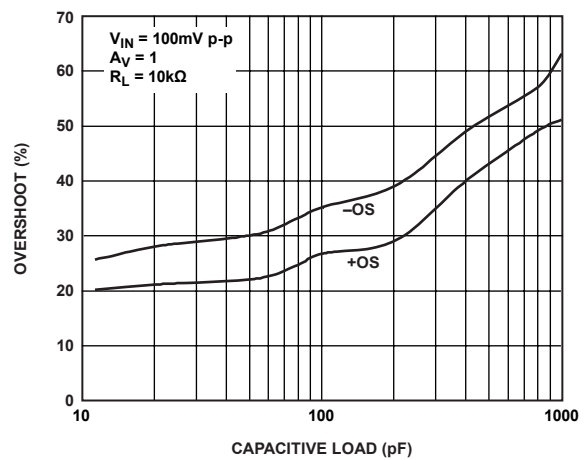
04889-025

Figure 25. Closed-Loop Output Impedance vs. Frequency



04889-023

Figure 23. Channel 6 to Channel 10 Frequency Response vs. Resistive Loading



04889-026

Figure 26. Channel 1 to Channel 5 Small Signal Overshoot vs. Load Capacitance

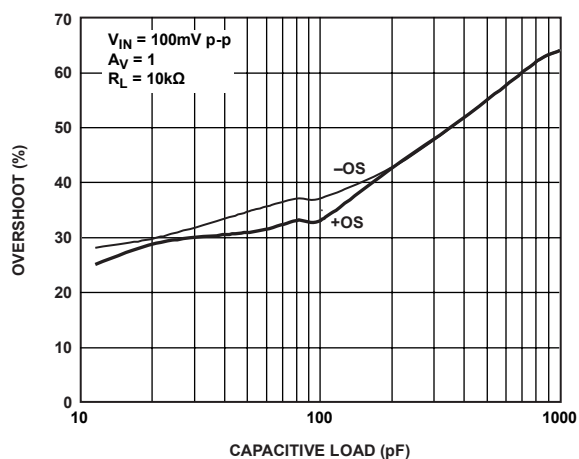


Figure 27. Channel 6 to Channel 10 Small Signal Overshoot vs. Load Capacitance

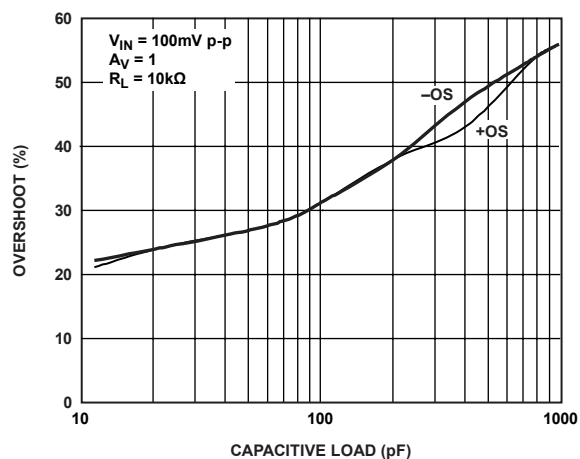
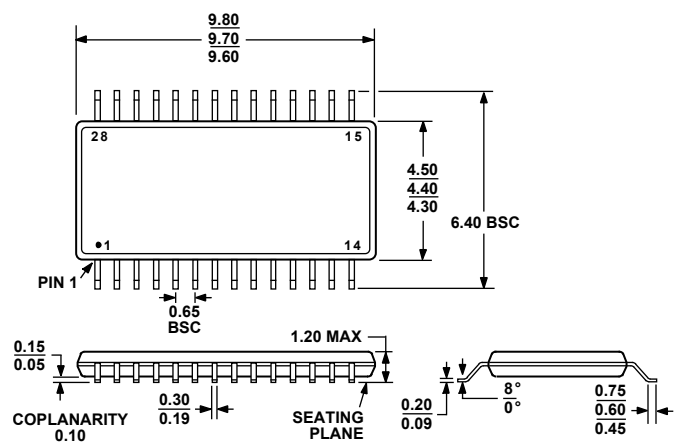


Figure 28. Channel V_{COM} Small Signal Overshoot vs. Load Capacitance

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153-AE
Figure 29. 28-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-28)
Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
ADD8710ARUZ ¹	−40°C to +85°C	28-Lead TSSOP	RU-28
ADD8710ARUZ-REEL ¹	−40°C to +85°C	28-Lead TSSOP	RU-28

¹ Z = RoHS Compliant Part.

NOTES

ADD8710

NOTES